



60V 175°C DUAL N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
60V	25mΩ @ V _{GS} = 10V	32A
60 V	$40 \text{m}\Omega$ @ V _{GS} = 4.5V	25A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Backlighting
- Power-management functions
- DC-DC converters

Features and Benefits

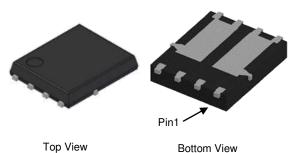
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMNH6021SPDQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

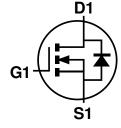
Mechanical Data

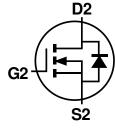
- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)

Site 1: PowerDI5060-8 (Type C)



Site 2:





D2

Equivalent Circuit

PowerDI5060-8/SWP (Type UXD)



Top View Bottom View

S1 [] D1
G1 [] D1
S2 [] D2

Pin out Top View

G1 S1

G2 (

Equivalent Circuit

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



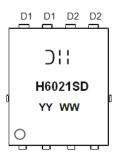
Ordering Information (Note 4)

Part Number	Pankago	Packing		
Fait Number	Package	Qty.	Carrier	
DMNH6021SPDQ-13	PowerDI5060-8 (Type C)	2,500	Tape & Reel	
DIVINHOUZ 13FDQ-13	PowerDI5060-8/SWP (Type UXD)		rape α neer	

Note:

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



O!! = Manufacturer's Marking
H6021SD = Product Type Marking Code
YYWW = Date Code Marking
YY or YY = Year (ex: 23 = 2023)
WW = Week (01 to 53)

Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V_{DSS}	60	V
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current (Note 6) V _{GS} = 10V	T _A = +25°C T _A = +70°C	lo	8.2 6.5	А
Continuous Drain Current (Note 7) V _{GS} = 10V	$T_C = +25$ °C $T_C = +100$ °C	I _D	32 22	А
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)	I _{DM}	80	Α	
Maximum Continuous Body Diode Forward Current (Note 8)	Is	32	Α	
Avalanche Current, L = 0.1mH (Note 8)		las	35	Α
Avalanche Energy, L = 0.1mH (Note 8)		Eas	64	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	В	99	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t < 10s	$R_{\theta JA}$	53	
Total Power Dissipation (Note 6)		PD	2.8	W
The served Decistors of Australia Austriant (Nata C)		Dove	54	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t < 10s	Reja	27	C/VV
Thermal Resistance, Junction to Case (Note 7)		R ₀ JC	2.2	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
- 7. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 8. IAS and EAS ratings are based on low frequency and duty cycles to keep $T_J = +25$ °C.

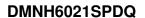


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

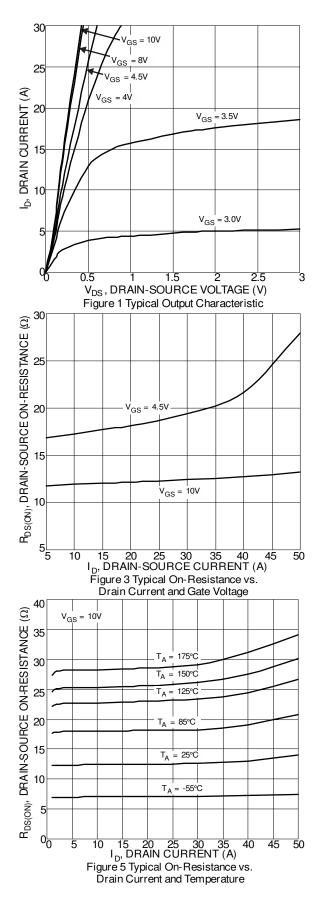
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)				•		•	
Drain-Source Breakdown Voltage	BVDSS	60	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	IDSS	_	_	1	μΑ	V _{DS} = 60V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 10)							
Gate Threshold Voltage	V _{GS(TH)}	1	_	3	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	Descent	_	15	25	mΩ	V _{GS} = 10V, I _D = 15A	
Static Drain-Source On-nesistance	RDS(ON)	_	21	40	mΩ	$V_{GS} = 4.5V, I_D = 12A$	
Diode Forward Voltage	V _{SD}	_	0.75	1.2	V	V _G S = 0V, I _S = 2.6A	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss		1,143	_	pF	V 05V V 0V	
Output Capacitance	Coss	_	168	_	pF	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz	
Reverse Transfer Capacitance	Crss	_	69	_	pF		
Gate Resistance	Rg	_	2.1	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 10V)	Qg	_	20.1	_	nC		
Total Gate Charge (VGS = 6V)	Qg	_	12	_	nC	\/ 20\/ I- 00A	
Gate-Source Charge	Qgs	_	4.3	_	nC	$V_{DS} = 30V, I_{D} = 20A$	
Gate-Drain Charge	Qgd	_	5.5	_	nC]	
Turn-On Delay Time	t _{D(ON)}	_	4.4	_	ns		
Turn-On Rise Time	tr	_	6.0	_	ns	V _{DD} = 30V, V _{GS} = 10V,	
Turn-Off Delay Time	tD(OFF)	_	14.2	_	ns	$R_G = 4.7\Omega$, $I_D = 20A$	
Turn-Off Fall Time	tF	_	5.4	_	ns		
Body Diode Reverse Recovery Time	trr	_	21.2	_	ns	I_ 004 di/dh 1004/us	
Body Diode Reverse Recovery Charge	Qrr		15.2	_	nC	-I _F = 20A, di/dt = 100A/μs	

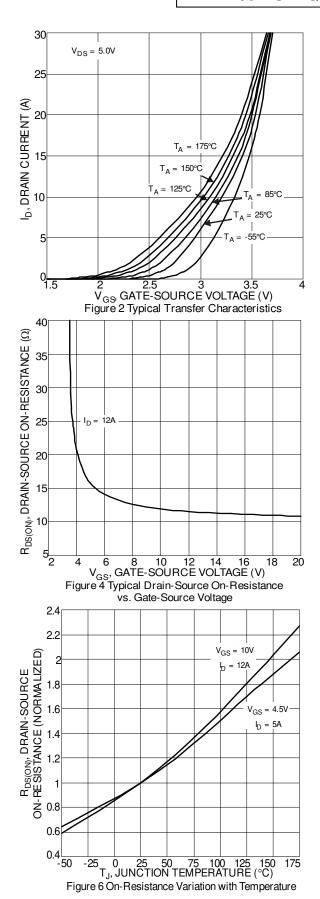
Notes:

Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.

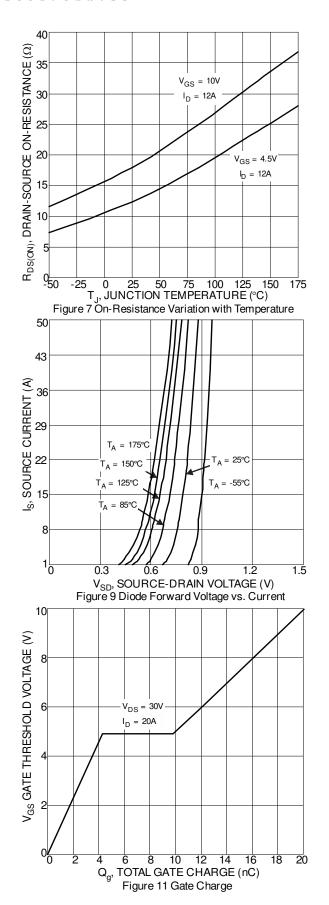


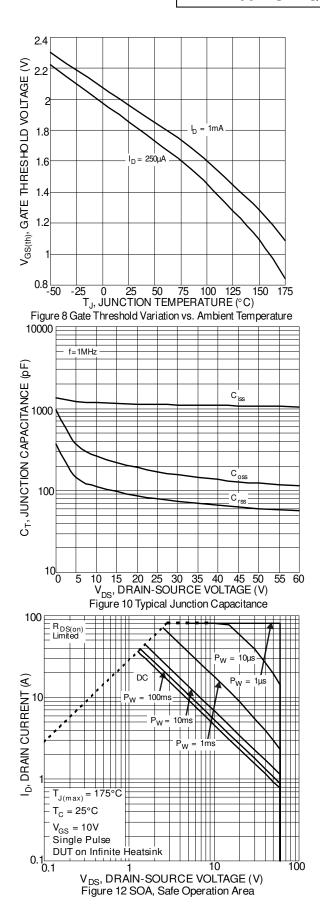




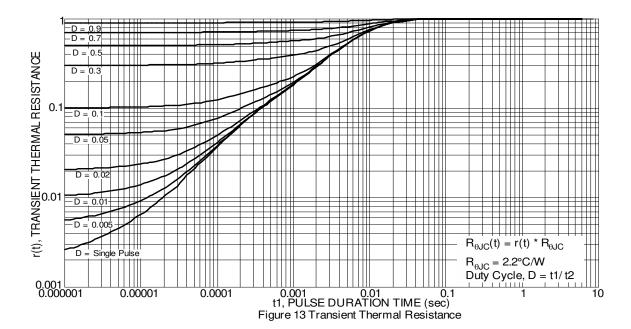












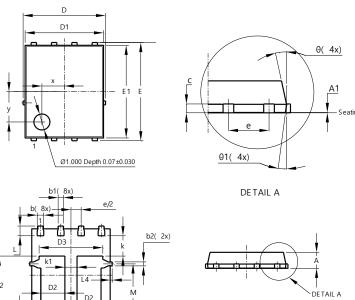


Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

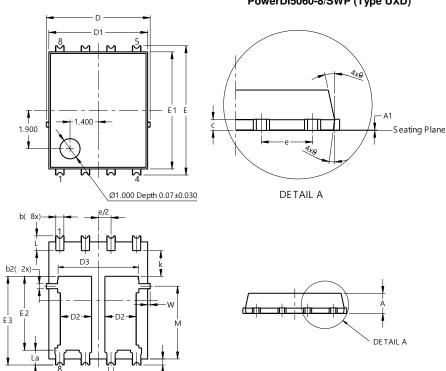
PowerDI5060-8 (Type C)



PowerDI5060-8 (Type C)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05	0.02	
b	0.33	0.51	0.41	
b1	0.300	0.366	0.333	
b2	0.20	0.35	0.25	
С	0.23	0.33	0.277	
D	5	.15 BS0	0	
D1	4.85	4.95	4.90	
D2	1.40	1.60	1.50	
D3	-	_	3.98	
Е	6	.15 BS0)	
E1	5.75	5.85	5.80	
E2	3.56	3.76	3.66	
е	1	.27BSC		
k	-	_	1.27	
k1	0.56	_	_	
L	0.51	0.71	0.61	
La	0.51	0.71	0.61	
L1	0.05	0.20	0.175	
L4	-	_	0.125	
М	3.50	3.71	3.605	
X	-	_	1.400	
у	ı	_	1.900	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All Dimensions in mm				

Site 2:

PowerDI5060-8/SWP (Type UXD)



(Type UXD)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A 1	0.00	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	C).25REF	-	
С	0.230	0.330	0.277	
D	5	.15 BS()	
D1	4.70	5.10	4.90	
D2	1.46	1.66	1.55	
D3	3.78	4.18	3.98	
Е	6	.40 BS0	\sim	
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е	1	.27BSC)	
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
М	3.205	4.005	3.605	
W	0.025	0.225	0.125	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All Dimensions in mm				

PowerDI5060-8/SWP

b4(8x)

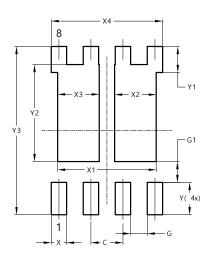


Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

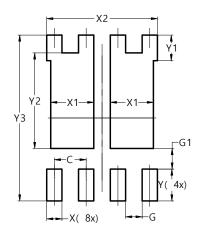
PowerDI5060-8 (Type C)



Dimensions	Value (in mm)	
С	1.270	
G	0.660	
G1	0.820	
X	0.610	
X1	3.910	
X2	1.650	
Х3	1.650	
X4	4.420	
Υ	1.270	
Y 1	1.020	
Y2	3.810	
Y3	6.610	

Site 2:

PowerDI5060-8/SWP (Type UXD)



Dimensions	Value
Difficusions	(in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	1.720
X2	4.420
Υ	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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